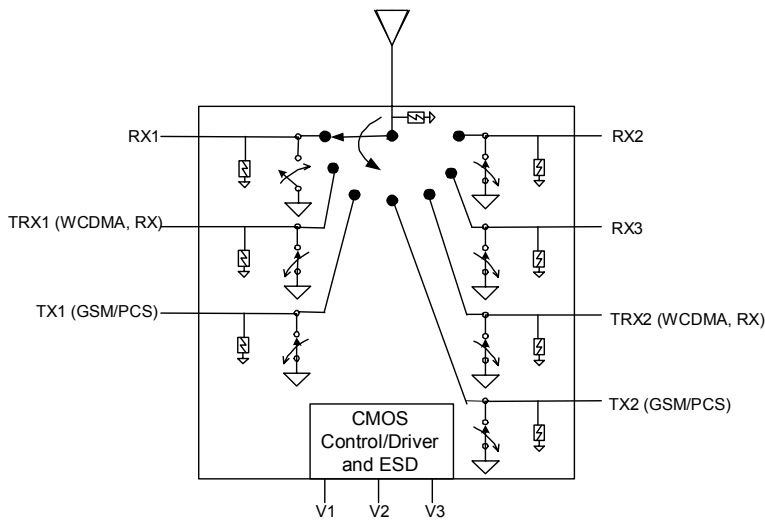
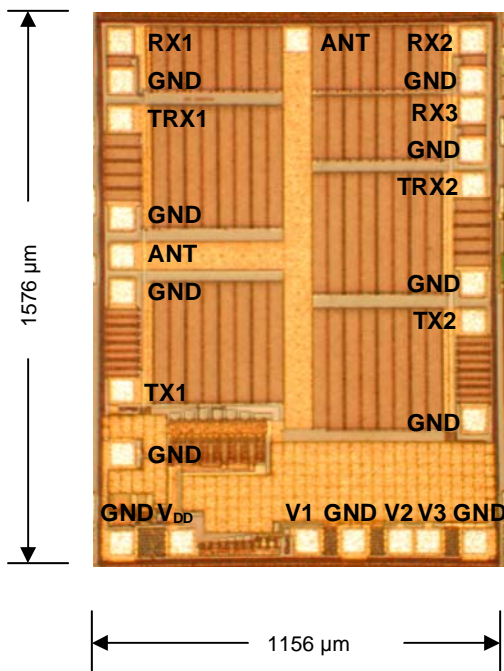


**SP7T UltraCMOS™ 2.75 V Switch**  
**100 – 3000 MHz, +68 dBm IIP3**

**Figure 1. Functional Diagram**



**Figure 2. Die Top View\***



\* Dimensions shown are drawn die size.

**Features**

- 2 TX, 2 TRX, 3 RX ports
- Three pin CMOS logic control with integral decoder/driver
- Exceptional harmonic performance:  $2f_o = -83$  dBc and  $3f_o = -78$  dBc
- Low TX insertion loss: 0.65 dB at 900 MHz, 0.75 dB at 1900 MHz
- TX – RX Isolation of 47 dB at 900 MHz, 40 dB at 1900 MHz
- 1500 V HBM ESD tolerance all ports
- +68 dBm IIP3 @ 50  $\Omega$
- -111 dBm IMD3
- No blocking capacitors required

**Product Description**

The PE42671 is a HaRP™-enhanced SP7T RF Switch developed on the UltraCMOS™ process technology. It addresses the specific design needs of the Quad-Band GSM Handset Antenna Switch Module Market for use in GSM/PCS/EDGE/WCDMA handsets. The switch is comprised of two transmit ports that can be used for GSM/PCS/EDGE, two transmit/receive ports (TRX1 and TRX2) that can be used for either WCDMA or as receive ports, and three symmetric receive ports. On-chip CMOS decode logic facilitates three-pin low voltage CMOS control, while high ESD tolerance of 1500 V at all ports, no blocking capacitor requirements, and on-chip SAW filter over-voltage protection devices make this the ultimate in integration and ruggedness.

Peregrine's HaRP™ technology enhancements deliver high linearity and exceptional harmonics performance. It is an innovative feature of the UltraCMOS™ process, providing performance superior to GaAs with the economy and integration of conventional CMOS.

**Table 1. Target Electrical Specifications @ 25 °C, V<sub>DD</sub> = 2.75 V**

Parameter	Condition	Typ	Units
Insertion loss <sup>1</sup>	TX - ANT (850 / 900)	0.65	dB
	TX - ANT (1800 / 1900)	0.75	dB
	TRX - ANT ( 850 WCDMA )	0.6	dB
	TRX - ANT ( 2100 WCDMA )	0.75	dB
	RX - ANT (850 / 900)	0.95	dB
	RX - ANT (1800 / 1900)	1.0	dB
Return Loss	Port under test in on state (850 / 900)	20	dB
	(1800 / 1900 / 2100)	15	dB
Isolation	TX - RX (850 / 900)	47	dB
	TX - RX (1800 / 1900)	40	dB
	TX - TX (850 / 900)	33	dB
	TX - TX (1800 / 1900)	27	dB
	TX - TRX (850 / 900)	36	dB
	TX - TRX (1800 / 1900)	29	dB
	TRX - RX ( 850 WCDMA )	40	dB
TRX - RX (2100 WCDMA)	31	dB	
2nd Harmonic	TX 850 / 900 MHz, +35 dBm output power, 50 Ω	-83	dBc
	TX 1800 / 1900 MHz, +33 dBm output power, 50 Ω	-82	dBc
3rd Harmonic	TX 850 / 900 MHz, +35 dBm output power, 50 Ω	-78	dBc
	TX 1800 / 1900 MHz, +33 dBm output power, 50 Ω	-78	dBc
WCDMA 2100 IMD3	TRX1 / TRX2: Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and -15 dBm CW signal at 1.76 GHz	-111	dBm
WCDMA 2100 IIP3	TRX1 / TRX2: Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and -15 dBm CW signal at 1.76 GHz	+68	dBm

Note: 1. Insertion loss specified with optimal impedance matching.

**Table 2. Operating Ranges**

Parameter	Symbol	Min	Typ	Max	Units
Temperature range	T <sub>OP</sub>	-40		+85	°C
V <sub>DD</sub> Supply Voltage	V <sub>DD</sub>	2.65	2.75	2.85	V
I <sub>DD</sub> Power Supply Current (V <sub>DD</sub> = 2.75 V)	I <sub>DD</sub>		13	50	μA
TX input power <sup>2</sup> (VSWR ≤ 3:1) 824-915 MHz	P <sub>IN</sub>			+35	dBm
TX input power <sup>2</sup> (VSWR ≤ 3:1) 1710-1910 MHz				+33	
TRX input power (VSWR ≤ 3:1) 824 - 2170 MHz				+31	
RX input power <sup>2</sup> (VSWR =1:1)	P <sub>IN</sub>			+20	dBm
Control Voltage High	V <sub>IH</sub>	1.4			V
Control Voltage Low	V <sub>IL</sub>			0.4	V

Note: 2. Assumes RF input period of 4620 μs and duty cycle of 50%.

**Table 3. Absolute Maximum Ratings**

Symbol	Parameter/Conditions	Min	Max	Units
V <sub>DD</sub>	Power supply voltage	-0.3	4.0	V
V <sub>I</sub>	Voltage on any input	-0.3	V <sub>DD</sub> + 0.3	V
T <sub>ST</sub>	Storage temperature range	-65	+150	°C
P <sub>IN</sub> (50 Ω)	TX input power (50 Ω) <sup>3,4</sup> 824-915 MHz		+38	dBm
	TX input power (50 Ω) <sup>3,4</sup> 1710-1910 MHz		+36	
	TRX input power (50 Ω) 824 - 2170 MHz		+34	
	RX input power (50 Ω) <sup>3,4</sup>		+23	
P <sub>IN</sub> (∞:1)	TX input power (VSWR = (∞:1) <sup>3,4</sup> 824-915 MHz		+35	dBm
	TX input power (VSWR = (∞:1) <sup>3,4</sup> 1710-1910 MHz		+33	
	TRX input power (VSWR = (∞:1) 824 - 2170 MHz		+31	
V <sub>ESD</sub>	ESD Voltage (HBM, MIL_STD 883 Method 3015.7)		1500	V

Note: 3. Assumes RF input period of 4620 μs and duty cycle of 50%.

4. V<sub>DD</sub> within operating range specified in Table 2.

Part performance is not guaranteed under these conditions. Exposure to absolute maximum conditions for extended periods of time may adversely affect reliability. Stresses in excess of absolute maximum ratings may cause permanent damage.

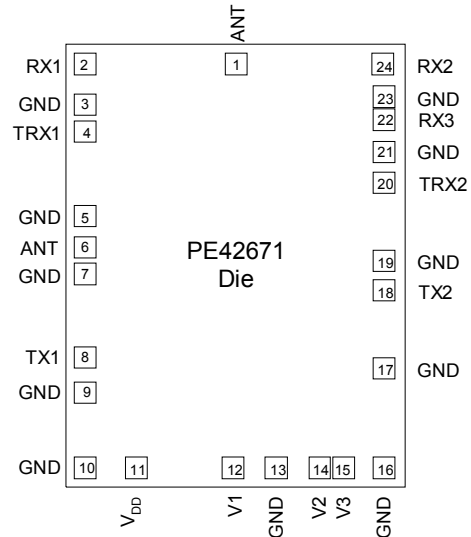
**Table 4. Pin Descriptions**

Pin No.	Pin Name	Description
1	ANT	RF Common – Antenna Redundant ANT pins for flexible bonding
2	RX1 <sup>6</sup>	RF I/O – RX1
3	GND <sup>5</sup>	Ground
4	TRX1 <sup>6</sup>	RF I/O – TRX1
5	GND <sup>5</sup>	Ground
6	ANT	RF Common – Antenna Redundant ANT pins for flexible bonding
7	GND <sup>5</sup>	Ground
8	TX1 <sup>6</sup>	RF I/O - TX1
9	GND <sup>5</sup>	Ground
10	GND <sup>5</sup>	Ground
11	V <sub>DD</sub>	Supply
12	V1	Switch control input, CMOS logic level
13	GND <sup>5</sup>	Ground
14	V2	Switch control input, CMOS logic level
15	V3	Switch control input, CMOS logic level
16	GND <sup>5</sup>	Ground
17	GND <sup>5</sup>	Ground
18	TX2 <sup>6</sup>	RF I/O – TX2
19	GND <sup>5</sup>	Ground
20	TRX2 <sup>6</sup>	RF I/O – TRX2
21	GND <sup>5</sup>	Ground
22	RX3 <sup>6</sup>	RF I/O – RX3
23	GND <sup>5</sup>	Ground
24	RX2 <sup>6</sup>	RF I/O – RX2

Notes: 5. Bond wires should be physically short and connected to ground plane for best performance.

6. Blocking capacitors needed only when non-zero DC voltage present.

**Figure 3. Pad Configuration (Top View)**



**Table 5. Truth Table**

Path	V3	V2	V1
TX1 - ANT	0	0	0
TX2 - ANT	0	0	1
TRX1 - ANT	0	1	0
TRX2 - ANT	1	1	0
RX1 - ANT	0	1	1
RX2 - ANT	1	0	0
RX3 - ANT	1	0	1

### Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

### Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

**Table 6. Ordering Information**

Order Code	Description	Package	Shipping Method
42671-90	PE42671-DIE-D	Film Frame	Wafer (Gross Die / Wafer Quantity)
42671-99	PE42671-DIE-400G	Waffle Pack	400 Dice / Waffle Pack
42671-00	PE42671-DIE-1H	Evaluation Kit	1/ box

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